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May 2010



## KSC5305D NPN Silicon Transistor

### Features

- High Voltage High Speed Power Switch Application
- · Built-in Free-wheeling Diode makes efficient anti saturation operation
- Suitable for half bridge light ballast Applications
- No need to interest an h<sub>FE</sub> value because of low variable storage-time spread even though corner spirit product
- · Low base drive requirement



### Absolute Maximum Ratings T<sub>a</sub> = 25°C unless otherwise noted

Symbol	Parameter	Value	Units	
V <sub>CBO</sub>	Collector Base Voltage	800	V	
V <sub>CEO</sub>	Collector Emitter Voltage	400	V V	
V <sub>EBO</sub>	Emitter Base Voltage	12		
Ι <sub>C</sub>	Collector Current (DC)	5	А	
I <sub>CP</sub>	*Collector Current (Pulse)	10	А	
Ι <sub>Β</sub>	Base Current (DC)	2	А	
I <sub>BP</sub>	*Base Current (Pulse)	4	А	
P <sub>C</sub> Power Dissipation (T <sub>C</sub> =25°C)		75	W	
Т <sub>Ј</sub>	Γ <sub>J</sub> Junction Temperature 150		°C	
T <sub>STG</sub>	Storage Temperature	- 65 to 150	°C	

\* Pulse Test : Pulse Width = 5mS, Duty cycles  $\leq$  10%

### **Thermal Characteristics**

Symbol	Parameter		Rating	Units	
R <sub>θjc</sub>	Thermal Resistance	Junction to Case	1.65	°C/W	
$R_{ heta ja}$		Junction to Ambient	62.5	°C/W	

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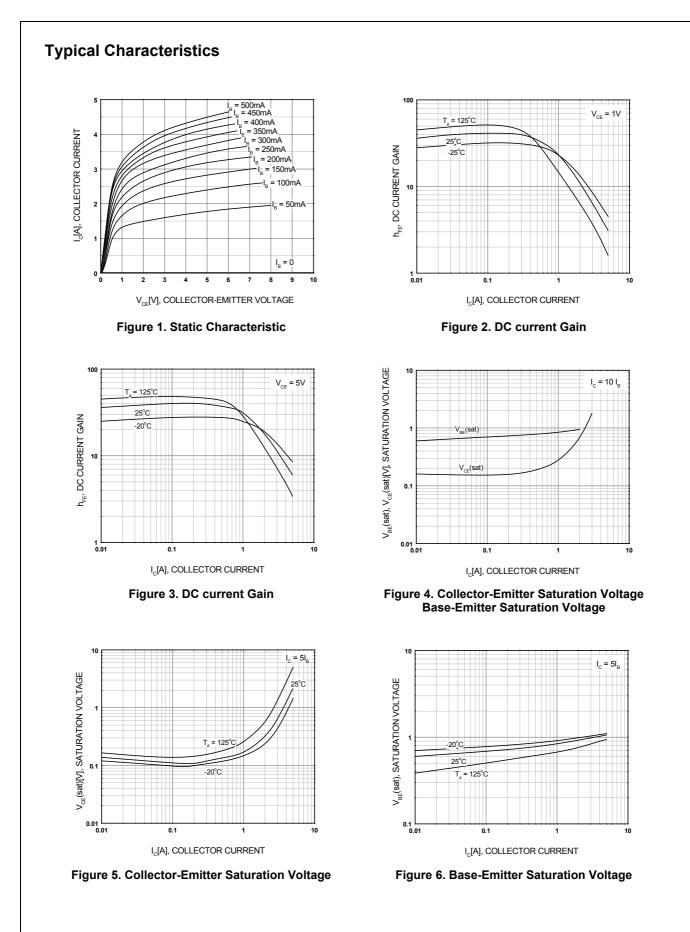
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Symbol	Parameter	Test Condition	Min.	Тур.	Max.	Units
BV <sub>CBO</sub>	Collector-Base Breakdown Voltage	I <sub>C</sub> =1mA, I <sub>E</sub> =0	800	-	-	V
BV <sub>CEO</sub>	Collector-Emitter Breakdown Voltage	I <sub>C</sub> =5mA, I <sub>B</sub> =0	400	-	-	V
$BV_{EBO}$	Emitter-Base Breakdown Voltage	I <sub>E</sub> =1mA, I <sub>C</sub> =0	12	-	-	V
I <sub>CBO</sub>	Collector Cut-off Current	V <sub>CB</sub> =500V, I <sub>E</sub> =0	-	-	10	μA
I <sub>EBO</sub>	Emitter Cut-off Current	V <sub>EB</sub> = 9V, I <sub>C</sub> = 0	-	-	10	μA
h <sub>FE1</sub> h <sub>FE2</sub>	DC Current Gain	V <sub>CE</sub> =1V, I <sub>C</sub> =0.8A V <sub>CE</sub> =1V, I <sub>C</sub> =2A	22 8	-	-	
V <sub>CE</sub> (sat)	Collector-Emitter Saturation Voltage	I <sub>C</sub> =0.8A, I <sub>B</sub> =0.08A I <sub>C</sub> =2A, I <sub>B</sub> =0.4A	-	-	0.4 0.5	V V
V <sub>BE</sub> (sat)	Base-Emitter Saturation Voltage	I <sub>C</sub> =0.8A, I <sub>B</sub> =0.08A I <sub>C</sub> =2A, I <sub>B</sub> =0.4A	-	-	1.0 1.0	V V
C <sub>ob</sub>	Output Capacitance	V <sub>CB</sub> =10V, f=1MHz	-	-	75	pF
t <sub>ON</sub>	Turn On Time	$V_{CC}$ =300V, I <sub>C</sub> =2A, I <sub>B1</sub> =0.4A, I <sub>B2</sub> =-1A, R <sub>L</sub> =150Ω	-	-	150	ns
t <sub>STG</sub>	Storage Time		-	-	2	μS
t <sub>F</sub>	Fall Time		-	-	0.2	μS
t <sub>STG</sub>	Storage Time	V <sub>CC</sub> =15V, V <sub>Z</sub> =300V,	-	-	2.25	μS
t <sub>F</sub>	Fall Time	I <sub>C</sub> =2A, I <sub>B1</sub> =0.4A, I <sub>B2</sub> =-0.4A, L <sub>C</sub> =200μH	-	-	150	ns
V <sub>F</sub>	Diode Forward Voltage	I <sub>F</sub> =1A	-	-	1.5	V
		I <sub>F</sub> =2A	-	-	1.6	V
t <sub>rr</sub>	* Reverse recovery time	I <sub>F</sub> =0.4A	-	800	-	ns
	(di/dt = 10A/µs)	I <sub>F</sub> =1A I <sub>F</sub> =2A	-	1.4 1.9	-	μS μS

### Electrical Characteristics T<sub>a</sub>=25°C unless otherwise noted

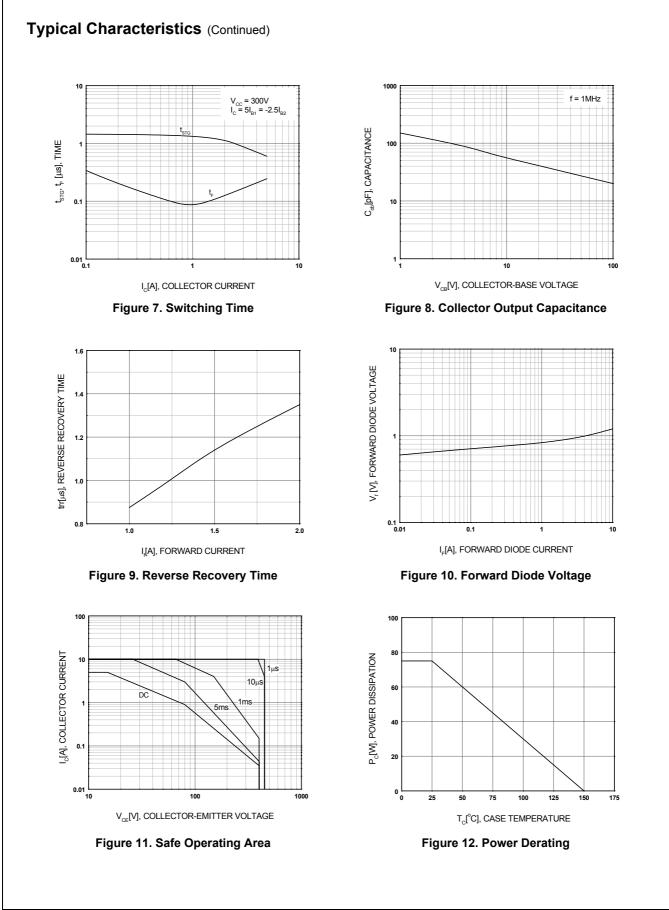
\* Pulse Test : Pulse Width = 5mS, Duty cycles  $\leq$  10%

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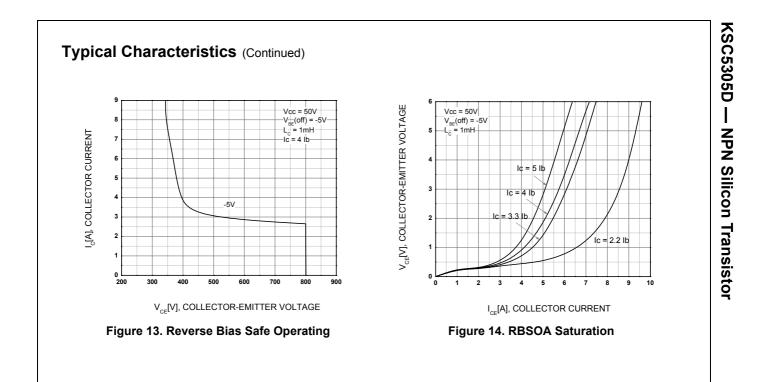


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